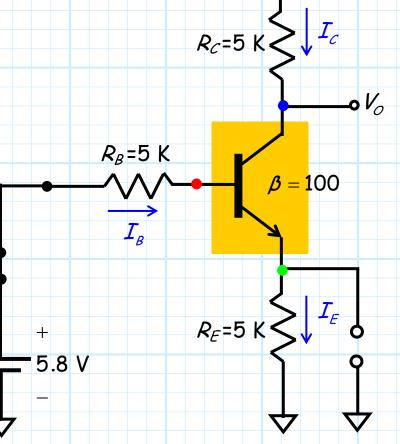


15.0 V

To do this, we must follow each of our **five** small-signal analysis **steps**!

<u>Step 1</u>: Complete a D.C. Analysis

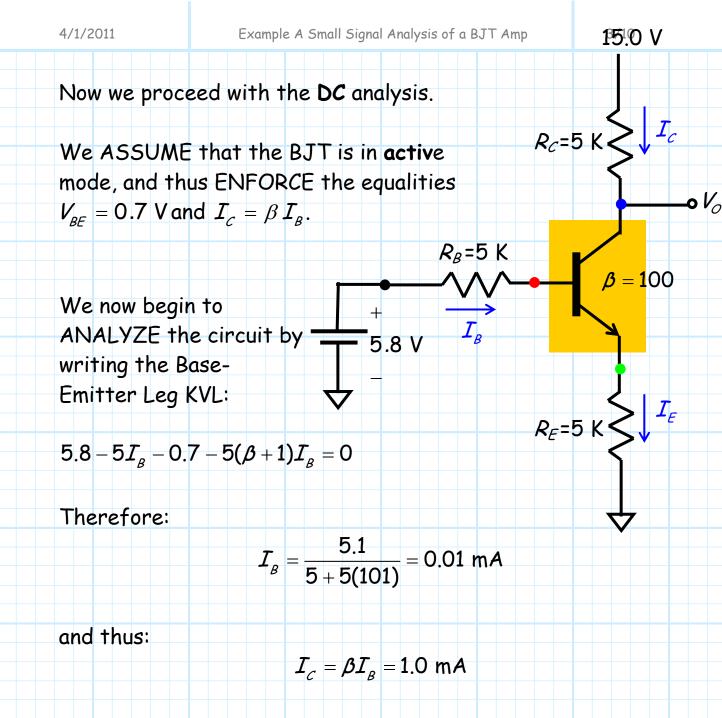
The **DC circuit** that we must analyze is:



Note what we have done to the original circuit:

1) We turned **off** the **small-signal** voltage source $(v_i(t) = 0)$, thus replacing it with a **short** circuit.

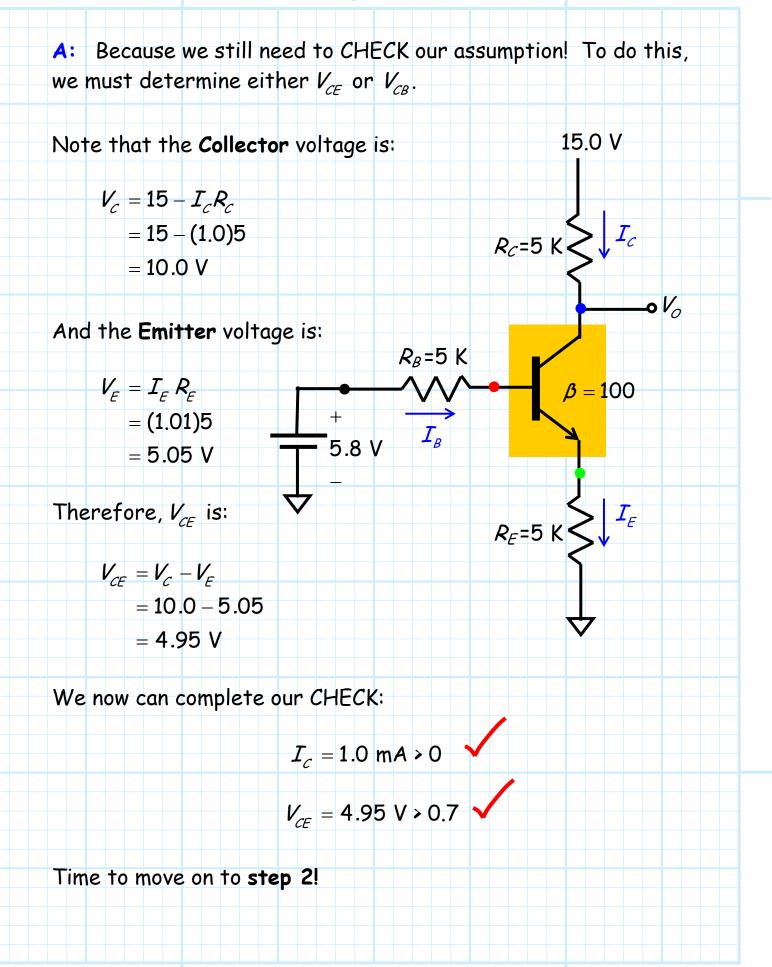
2) We replaced the **capacitor** with an **open** circuit—its DC impedance.



$$I_E = I_B + I_C = 1.01 \text{ mA}$$

Q: Since we know the DC bias currents, we have **all** the information we need to determine the **small-signal parameters**.

Why don't we proceed directly to step 2?



<u>Step 2:</u> Calculate the small-signal circuit parameters for each BJT.

If we use the Hybrid-II model, we need to determine g_m and r_{π} :

$$g_m = \frac{I_c}{V_T} = \frac{1.0 \ mA}{0.025V} = 40 \ \frac{mA}{V}$$

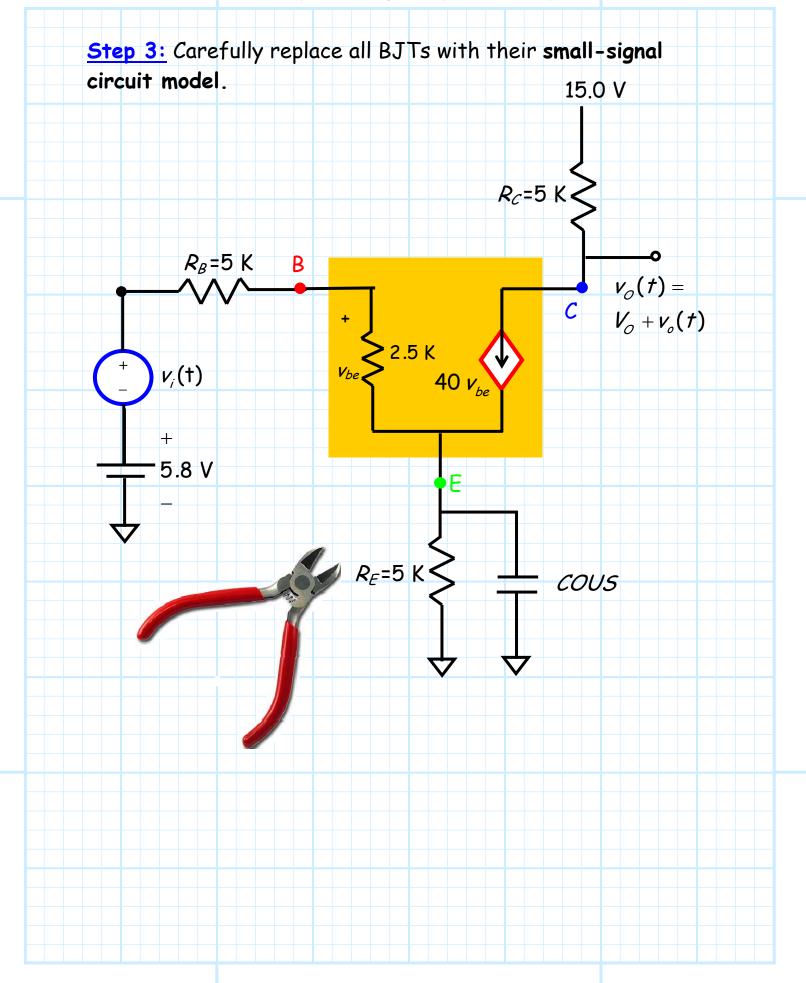
 $r_{\pi} = \frac{V_{T}}{I_{B}} = \frac{0.025 \text{ V}}{0.01 \text{ mA}} = 2.5 \text{ K}$

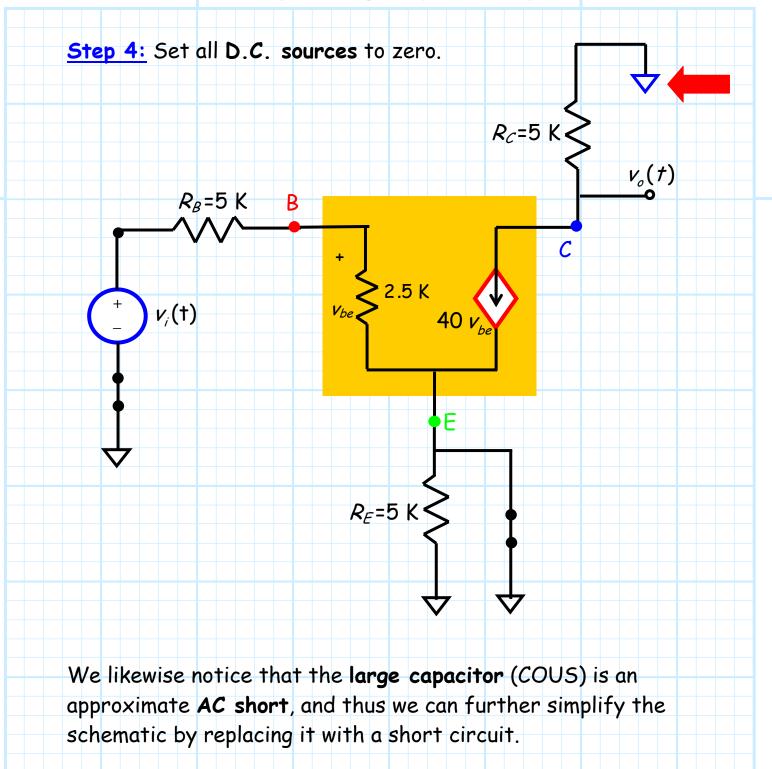
If we were to use the **T-model** we would likewise need to determine the emitter resistance:

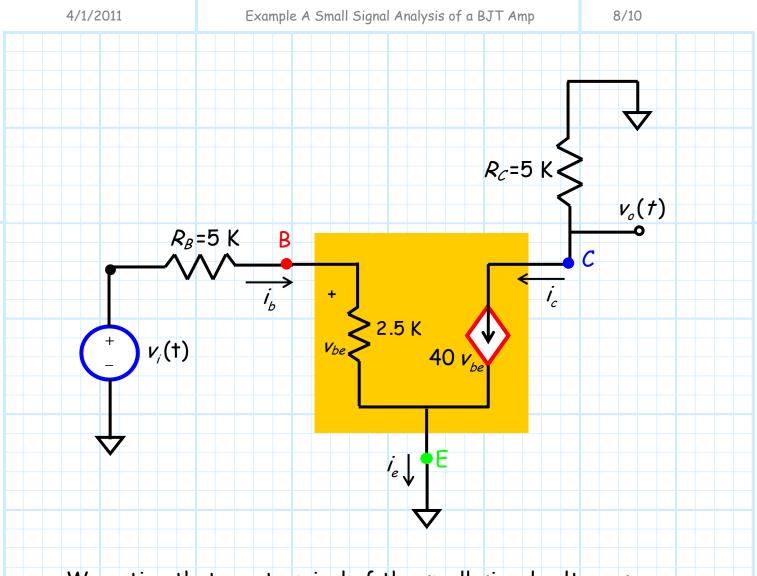
$$r_e = \frac{V_T}{I_B} = \frac{0.025 \text{ V}}{1.01 \text{ mA}} = 24.7 \Omega$$

The **Early voltage** V_A of this BJT is unknown, so we will **neglect** the Early effect in our analysis.

As such, we assume that the output resistance is infinite $(r_o = \infty)$.

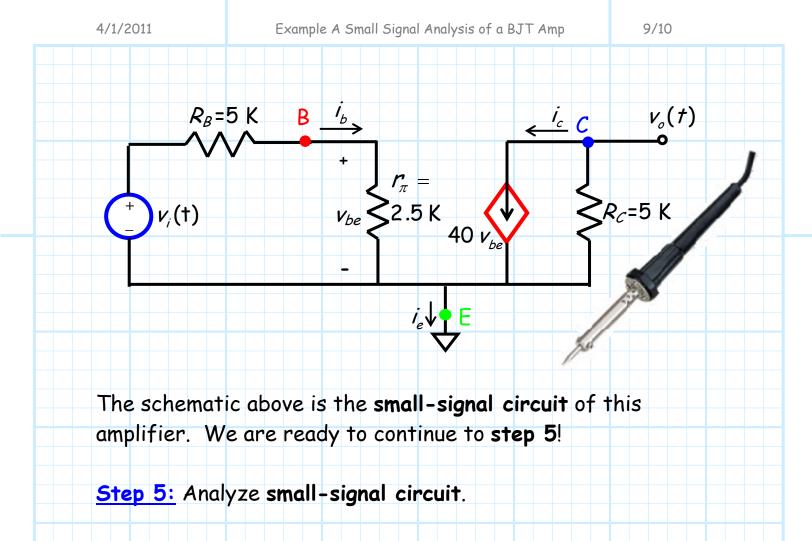






We notice that one terminal of the small-signal voltage source, the emitter terminal, and one terminal of the collector resistor R_c are all connected to ground—thus they are all collected to each other!

We can use this fact to simplify the small-signal schematic.



This is just a simple **EECS 211** problem! The **left** side of the circuit provides the **voltage divider** equation:

$$v_{be} = \frac{r_{\pi}}{R_{\beta} + r_{\pi}} v_i$$
$$= \frac{2.5}{5.0 + 2.5} v_i$$
$$= \frac{v_i}{3}$$

a result that relates the **input** signal to the base-emitter voltage.

